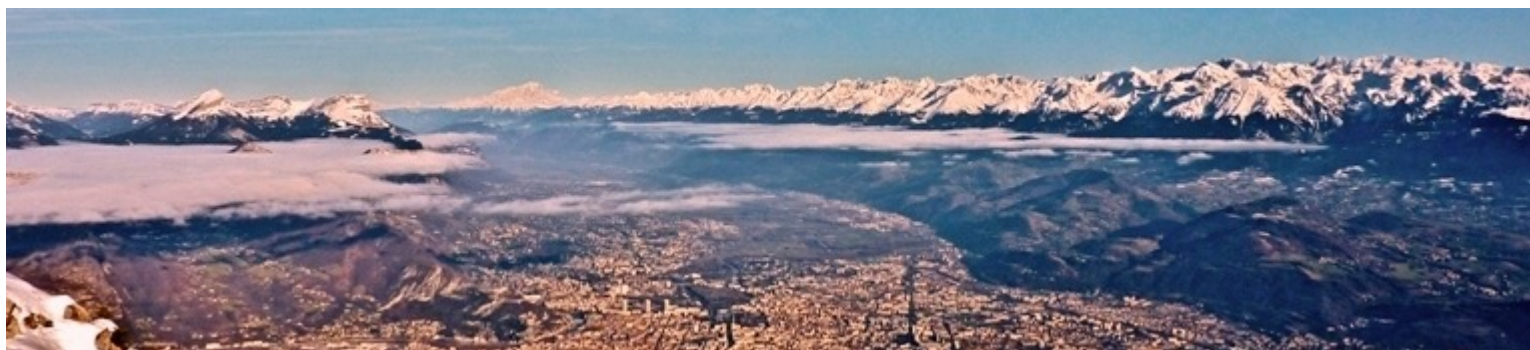


Large Area pcCVD diamond detectors and 3D Diamond Detectors

Michal Pomorski

Diamond Sensors Laboratory CEA-LIST



Journée d'étude sur les détecteurs diamant
09 June 2015, LPSC Grenoble

Introduction: Diamond Detectors

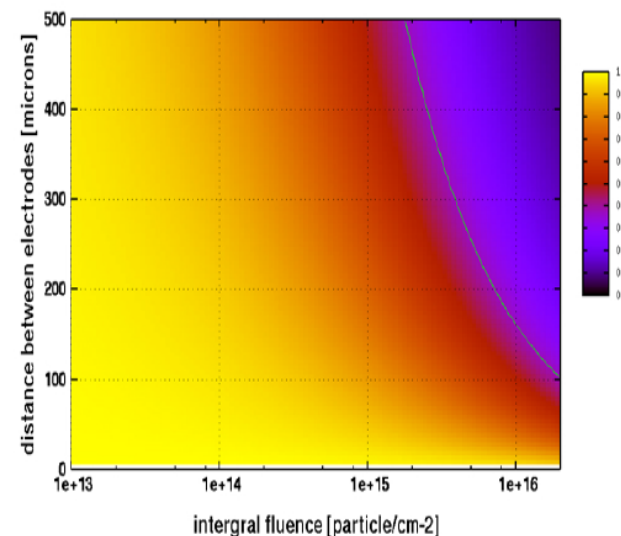
'Large Area' (LA) pcCVD: Experimental results (GamHadron)

3D Diamond Detectors: Status after 5 years of 'no-funds' project

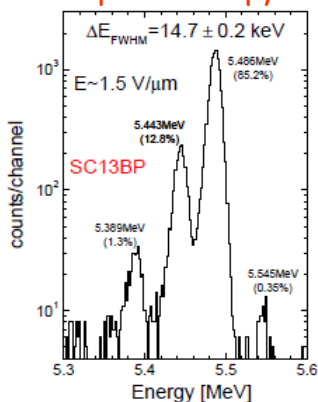
Introduction: Why Diamond

property	diamond	silicon	4H-SiC	detector operation
band gap [eV]	5.48	1.12	3.26	+ high T operation
dielectric strength [V/cm]	10^7^*	3×10^5	5×10^6	+ high field operation
intrinsic resistivity [Ω/cm]	$>> 10^{11}$	2.3×10^5	$> 10^5$	+ low leakage current
electron mobility [cm^2/Vs]	1900 – 4500*	1350	1000	+ fast signal
hole mobility [cm^2/Vs]	1800 – 3500*	480	115	+ fast signal
electron lifetime [s]	10^{-10} – 10^{-6}^*	$> 10^{-3}$	5×10^{-7}	+ full charge collection
hole lifetime [s]	10^{-10} – 10^{-6}^*	10^{-3}	7×10^{-7}	+ full charge collection
saturation velocity [cm/s]	$1.2 - 2.7 \times 10^7^*$	1×10^7	3.3×10^6	+ fast signal
density [g/cm^3]	3.52	2.33	3.21	
average atomic number	6	14	10	+ therapy - tissue equiv.
dielectric constant	5.72	11.9	9.7	+ low capacitance
displacement energy [eV]	43	13 – 20	20 – 35	+ radiation hardness
thermal conductivity [$\text{Wm}^{-1}\text{K}^{-1}$]	2000	150	120	+ heat dissipation
energy to create e-h [eV]	11.6 – 16*	3.62	7.8	- lower signal
radiation length, X_0 [cm]	12.2	9.36	8.7	+ low background
Energy loss for MIPs [MeV/cm]	4.69	3.21	4.32	
Aver. Signal Created / 100 μm	3602	8892	5100	+ lower signal
e-h pairs/ X_0 (10^6cm^{-1})	5.7	10	4.5	

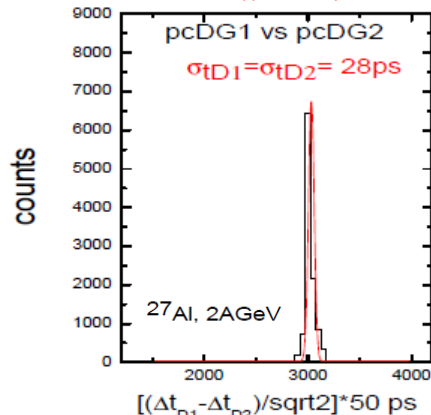
radiation hardness (26 MeV p)



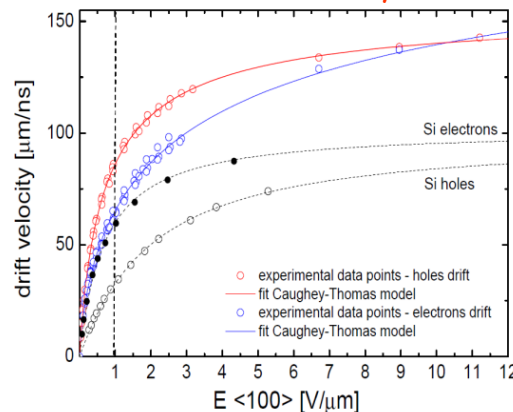
spectroscopy



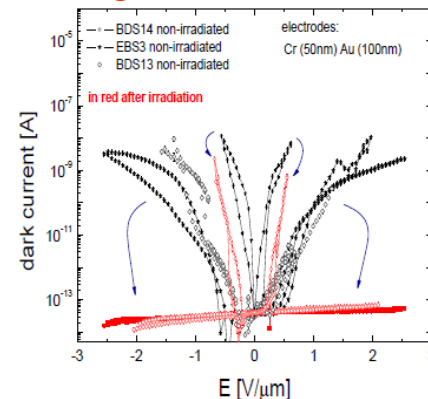
time res.



drift velocity



leakage current after irradi.



Introduction: Diamond Material

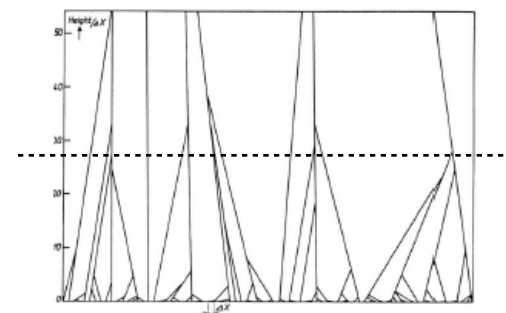
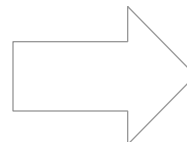
polycrystalline CVD diamond (pcCVD):

- atomic impurities [NO] → trapping
- grain boundaries 2D → 'erratic' currents, trapping
- inclusions (?)

best CCD/CCE: CCD ~300 microns (10k e/mip) (counting)

commercially available from Diamond Mat., E6, others(?)

up to 8 cm diam., price: ~ 1.5kGBP (10x10x0.5 mm) EL



single crystal CVD diamond (scCVD):

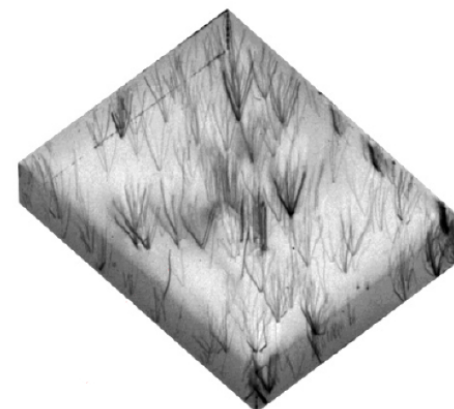
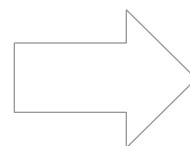
- atomic impurities [NO] → trapping
- dislocations → limited trapping, erratic currents, breakdown
- inclusions → erratic currents, breakdown

commercially available from e6, IIa techn.

up to 8x8 mm, price: ~ 1.5kGBP (4.5x4.5x0.3 mm) EL

R&D: 2 inch mosaic wafers (S. Shikata, Japan)

best CCD/CCE: 100% CCE for EG (500 microns) (spectroscopic)



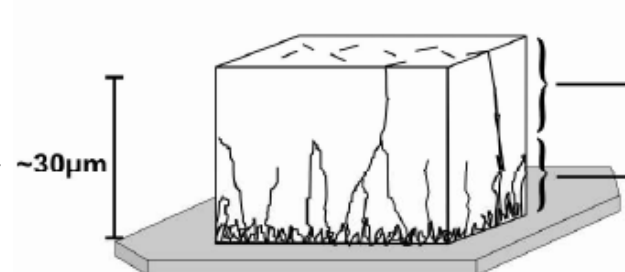
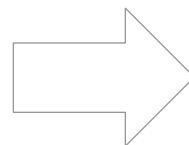
diamond on iridium DoI (CVD):

- atomic impurities [NO]
- dislocations 1D (high density) - trapping
- inclusions(?)

R&D: 2x2 cm samples produced (Augsburg Univ.)

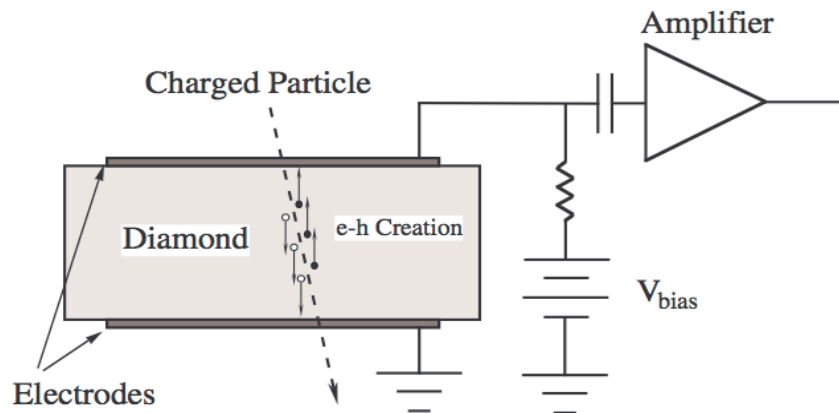
best CCD/CCE: approaching 100% (h) (almost spectroscopic)

low ~20% (e)



Introduction: Parallel Plates Diamond Detector

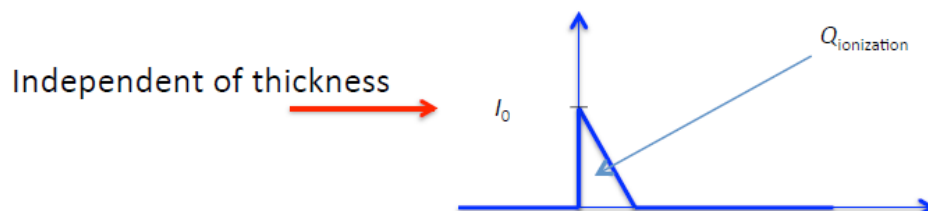
Schematic:



Ramo Current (traversing particle const. dE eg. a mip)

$$I_0 = \frac{Q_{ionization}}{d} \cdot V_d = \frac{dE}{dx} \cdot V_d$$

Bethe-Bloch



36 e-h/micron per mip

courtesy E. Griesmayer

ATLAS:

1 MIP

1 uA

in 50 Ω :

50 uV

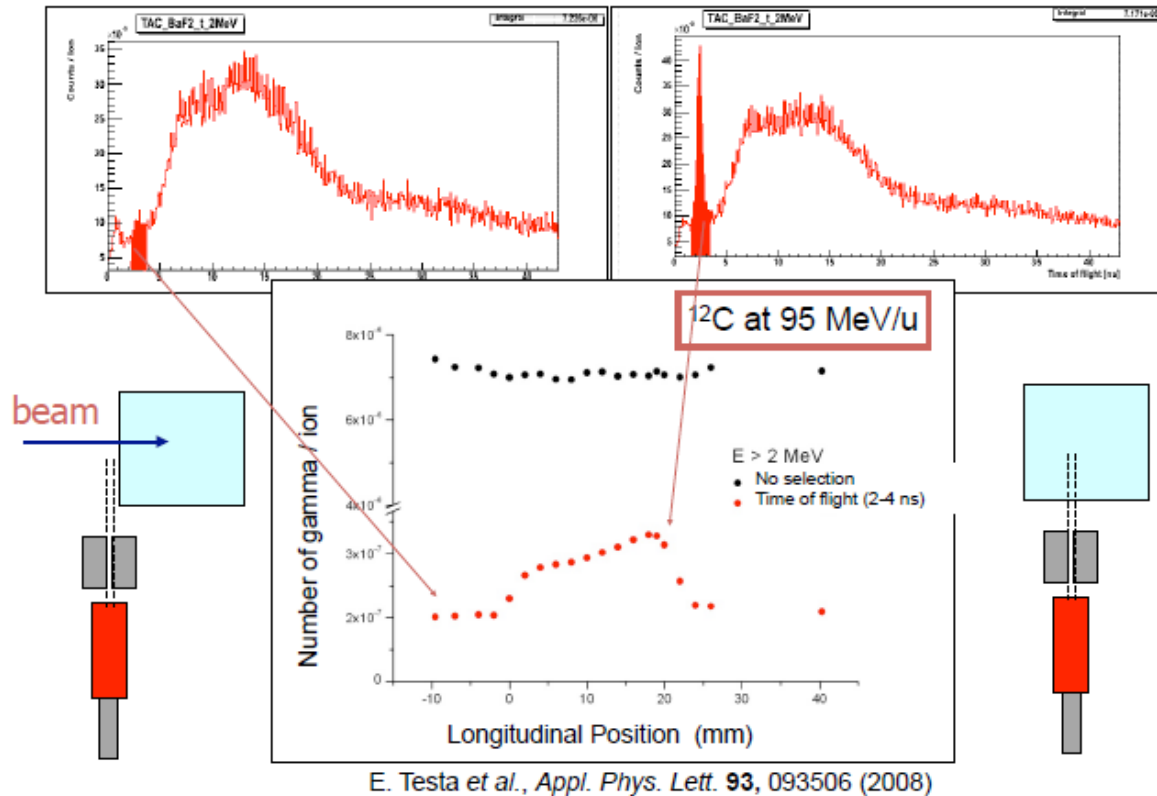
-> 40 dB gain

GamHadron - Compton Camera for in vivo real time dose imaging in hadron therapy

- IPN Lyon
- CREATIS Lyon
- LPC Clermont-Ferrand

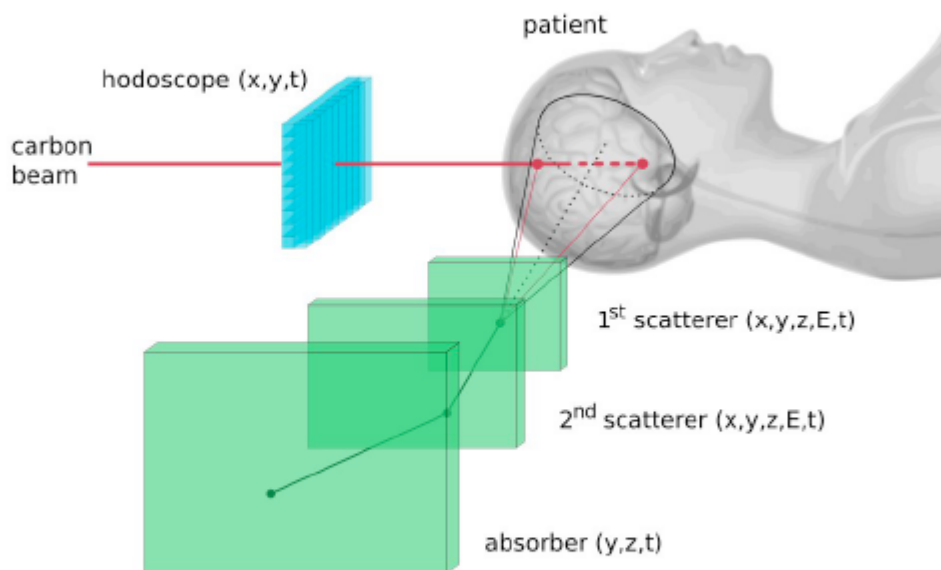
Large Area pcCVD: GamHadron

Prompt γ imaging: principle and feasibility studies



All content here Denis Dauvergne, IPN Lyon

A Beam-triggered Compton



- Initial design study: 3 interaction-system
- Hodoscope: x, y, T
- Reconstruction = line-cone intersection

Requirements for GamHadron Hodoscope:

- area $10 \times 10 \text{ cm}^2$
- position resolution $< 1 \text{ mm}$
- time resolution $< 1 \text{ ns}$
- rate capability $> 1 \text{ GHz/total area}$
- radiation hard

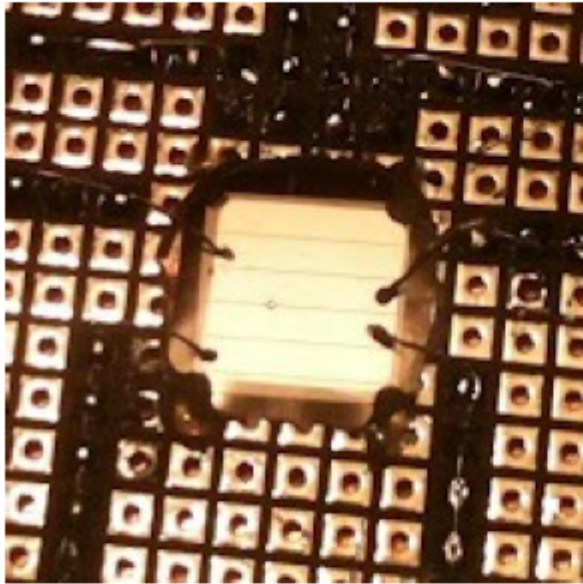
two candidates: scintilating fibers and diamond hodoscope

*diamond part co-authors@CEA-LIST: **Benoit Caylar, Dominique Tromson, Philippe Bergonzo***



Large Area pcCVD: Diamond Hodoscope

3 x 3 cm² pcCVD diamond forseen for the test crushed just three days before beamtime.....



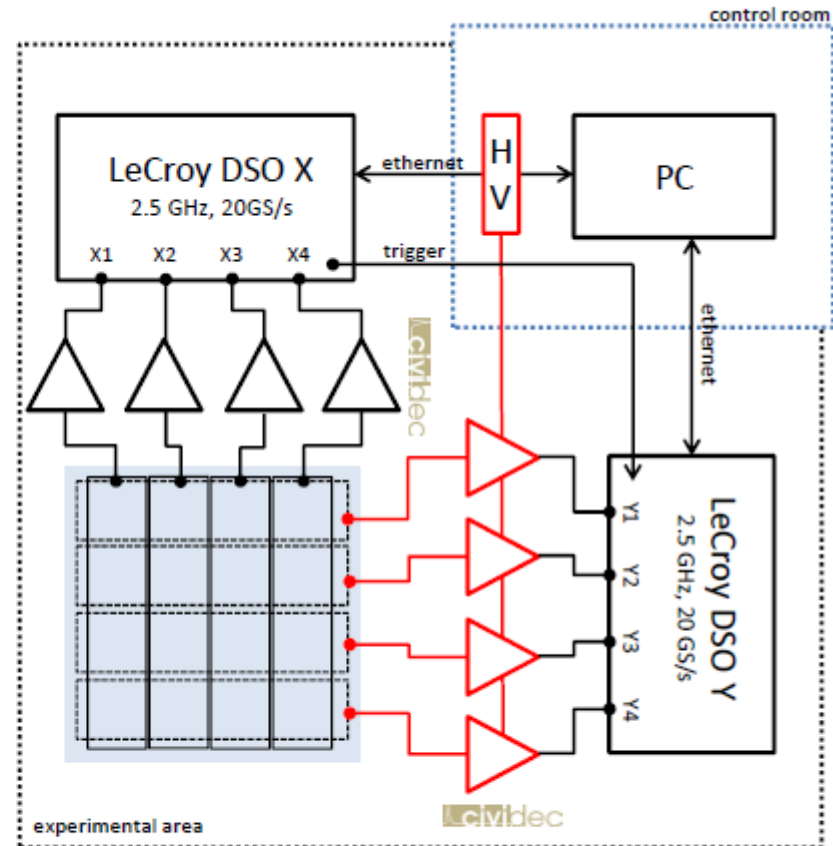
Final configuration:

1x1 cm² EG pcCVD diamond (500 μ m thick), Al 1.8 mm 4(X)x4(Y) strips with 100 μ m pitch

Large Area pcCVD: Electronics and DAQ



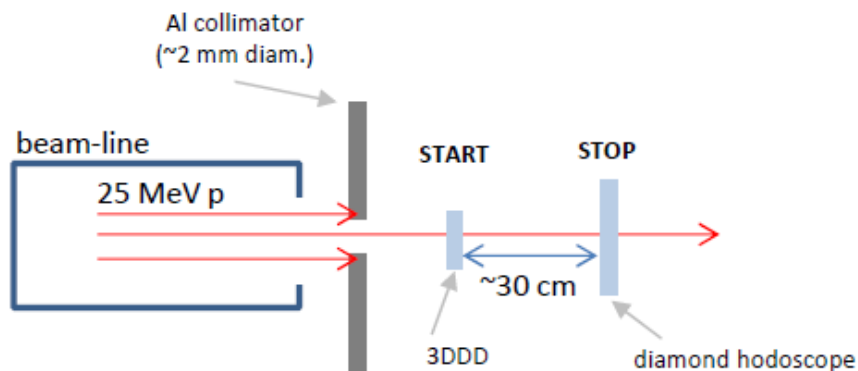
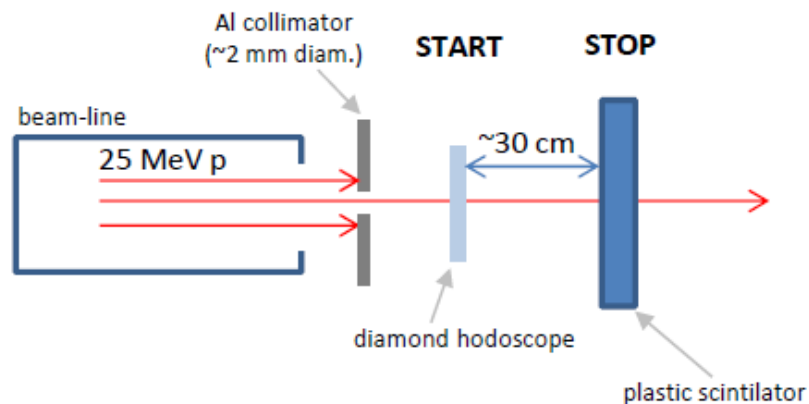
Laboratory testing with 5.48 MeV α source



Electronics (8x Cividec voltage amplifiers) and DAQ (2 x LeCroy 2GHz DSO)

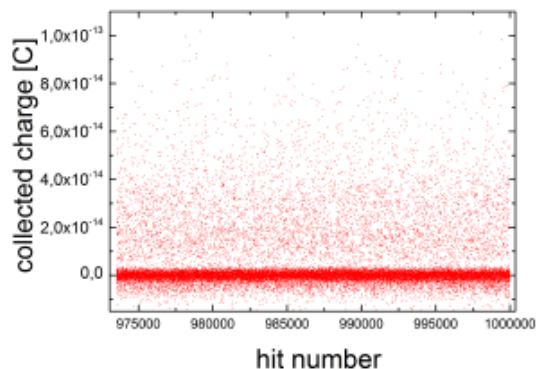
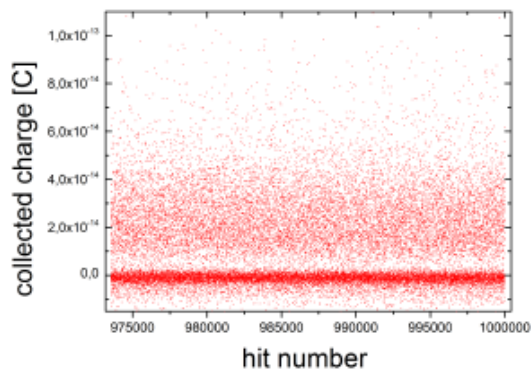
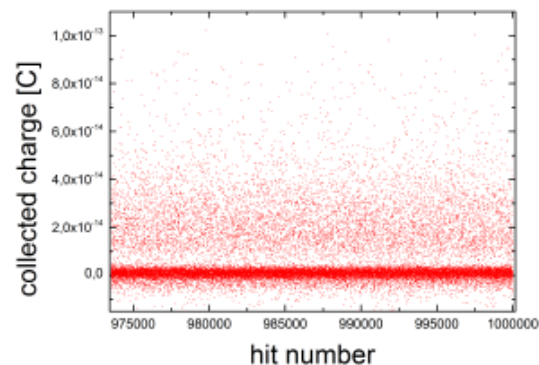
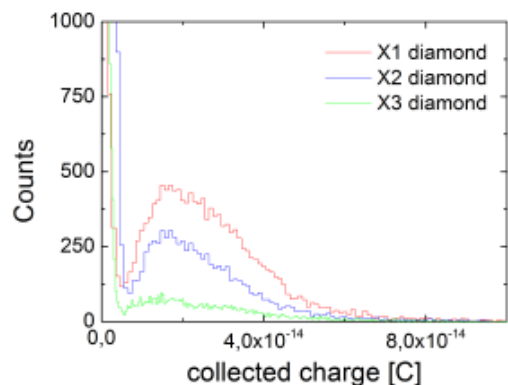
Large Area pcCVD: Beamtime setup

IPN Orsay tandem accelerator ALTO, 25 MeV p, 3.75 MeV deposited in 500 μm diamond



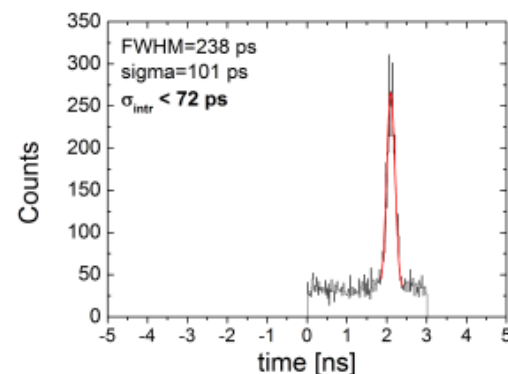
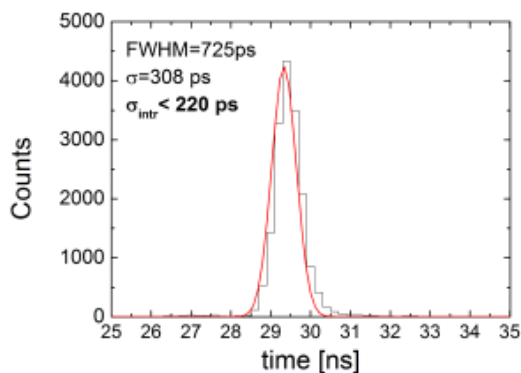
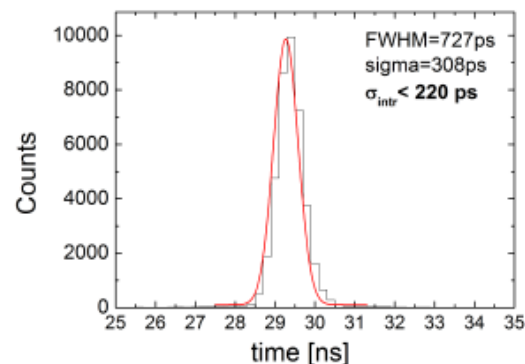
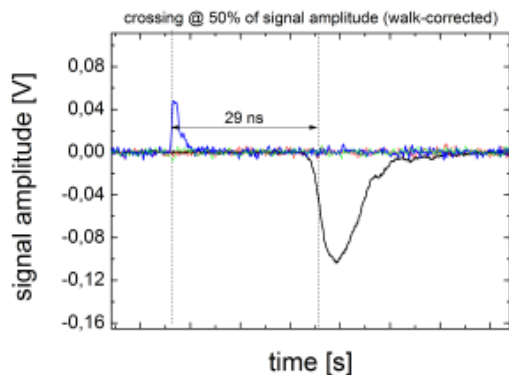
Large Area pcCVD: Charge Collection Spectra

Integral of current pulses for X1, X2, X3 strips from X plane, plastic trigger, HV = 700 V



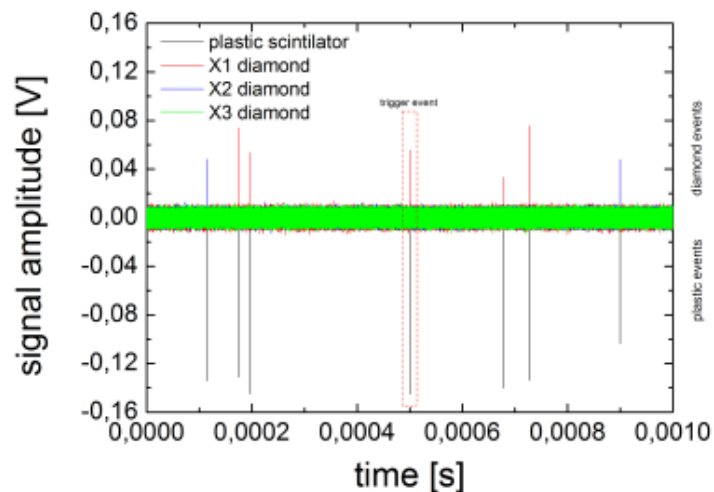
Large Area pcCVD: Time Measurements

Δt pcCVD diamond hodoscope (@700V) vs. plastic
and pcCVD hodoscope (@150V) vs. 3DDD (@150V)

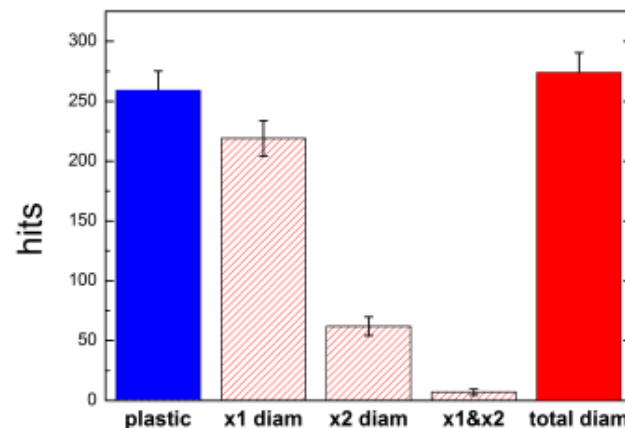


Large Area pcCVD: Detection Efficiency

About 100 random single-shots with aquisition time of 1 ms
trigger event = plastic and diamond X(i) coincidence



An example of single-shot

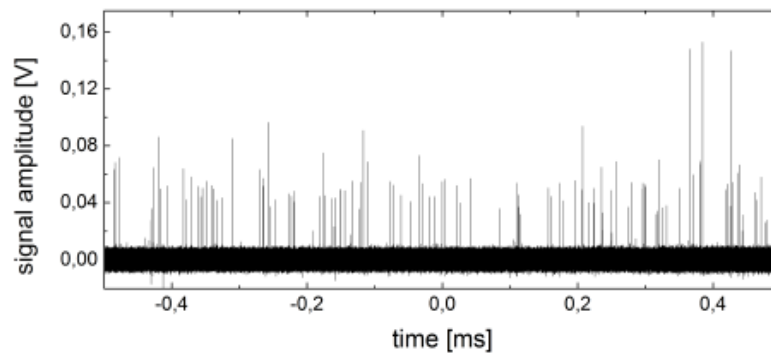
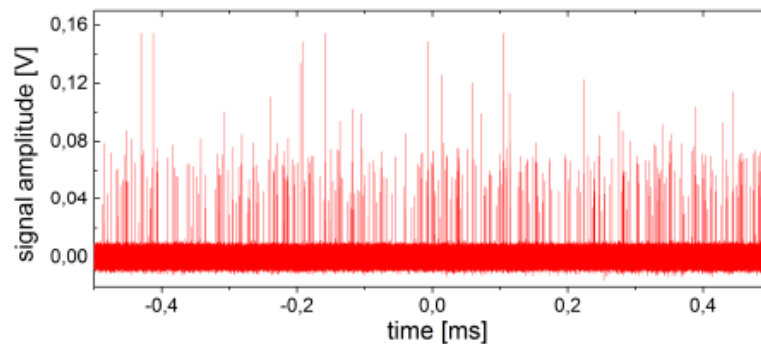


hit efficiency (inter-strip events corrected)

100% detection efficiency vs. plastic

Large Area pcCVD: High Rate

Plastic out of the beam, no collimator, asked operators for highest intensity possible ...



stable, no cross-talk

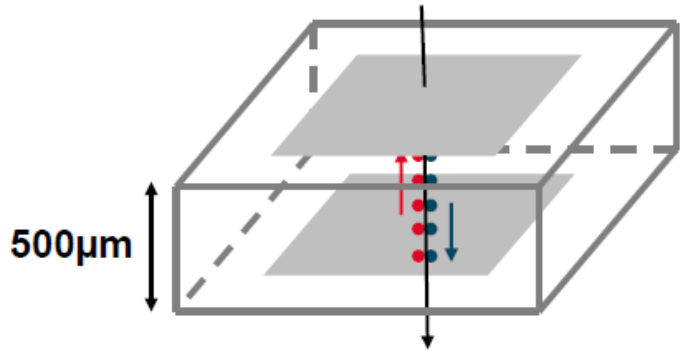
Large Area pcCVD: Summary

1 × 1 cm² pcCVD diamond double sided strip detector tested in 25 MeV proton beam. All requirements (apart of size.....) of GamHadron hodoscope fulfilled:

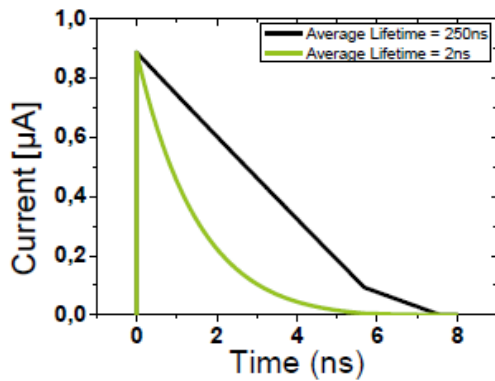
- position resolution - strip size limited (more precise for inter-strip events)
- time resolution $\sigma = 308$ ps (vs. plastic (plastic limited)) and $\sigma = 101$ ps (vs. 3DDD (low E field))
- rate capability (drift velocity limited) 0.1 GHz per strip for 500 μm thick
- stable operation, no evidence of cross-talk
- radiation hard (?)

3D Diamond Detectors - 3DDD

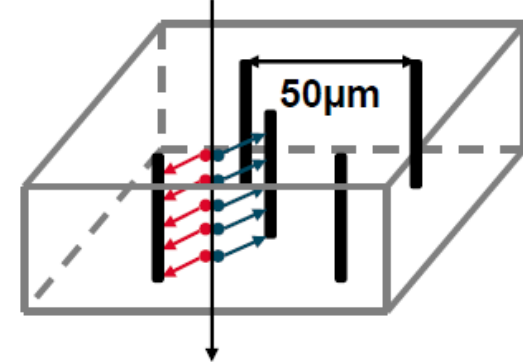
Planar geometry



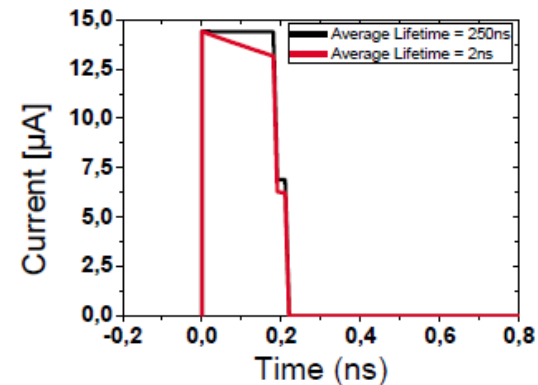
□ $Q_{MIP} = 18000$ e-h pairs



3D geometry



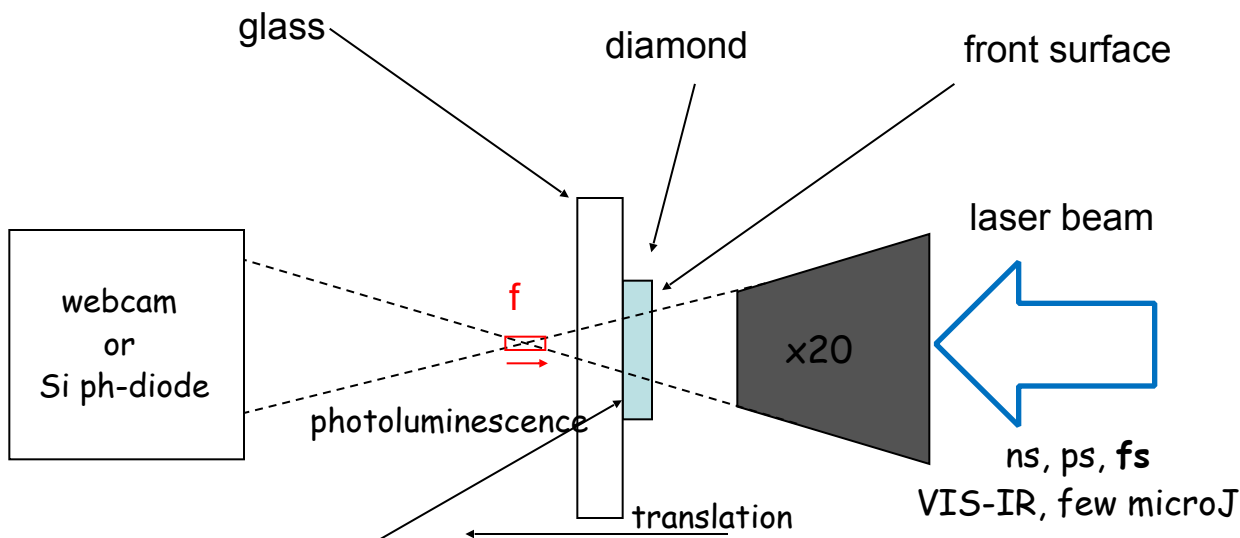
□ $Q_{MIP} = 18000$ e-h pairs



□ Analytically calculated currents generated by a MIP

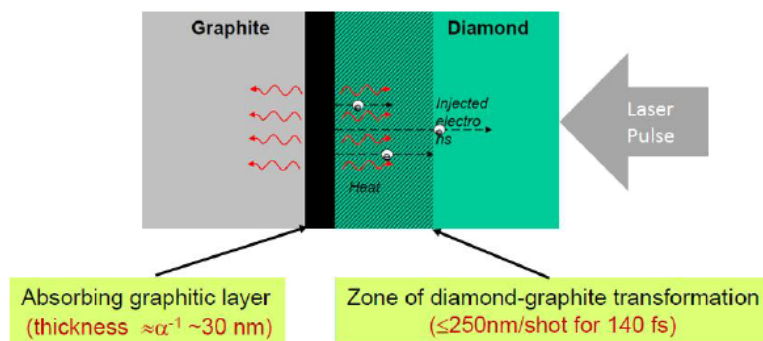
3DDD contributors@CEA-LIST: **Benoit Caylar, Dominique Tromson, Philippe Bergonzo**

3DDD - How to create conductive buried electrodes

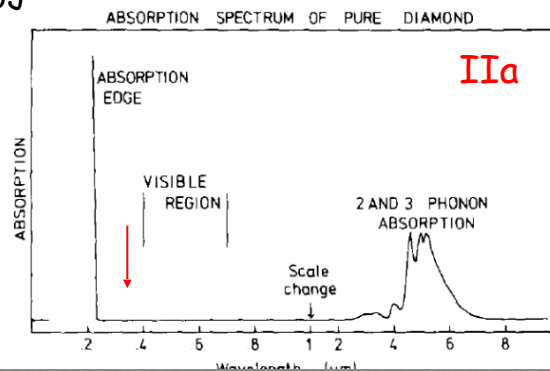


- holder-diamond interface
- graphitisation threshold
- focal within the bulk
- diamond-air interface
- surface damage

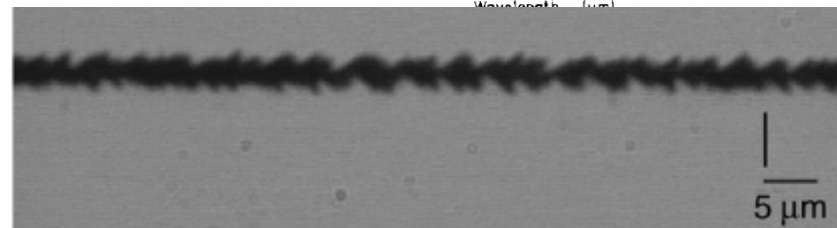
back surface (f entrance)



T.V. Kononenko et al – Rus'nanotech (2010)



No heat accumulation



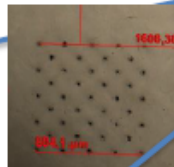
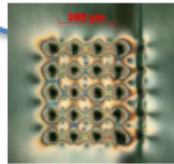
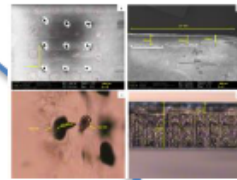
3D Diamond Research

Lasered graphitic structures
in pCVD ('10)

Single crystal with column
structure ('11)

Femto second laser for
improved graphitic
electrodes ('12)

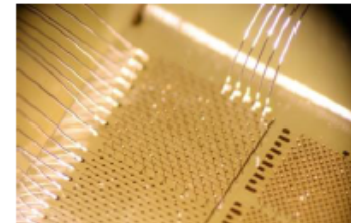
Improved laser processing
and TCAD simulation ('13)



3DD

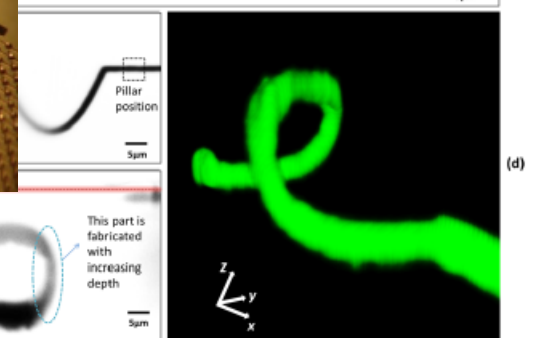
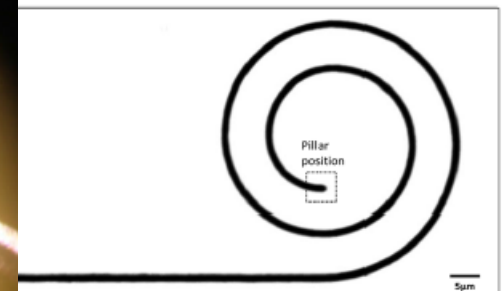
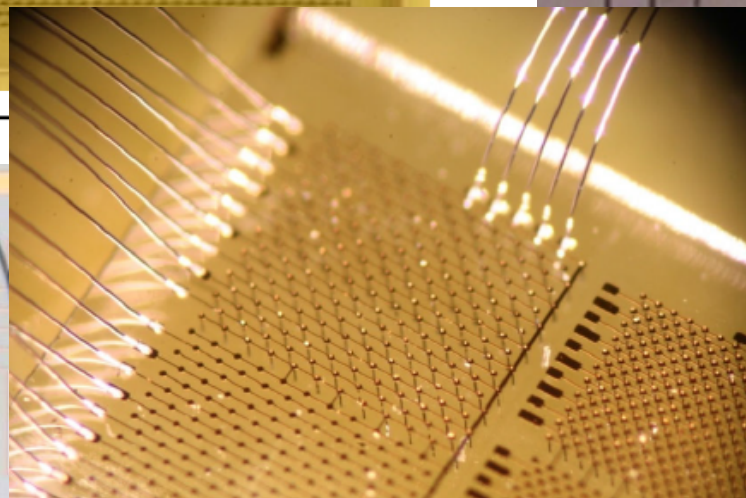
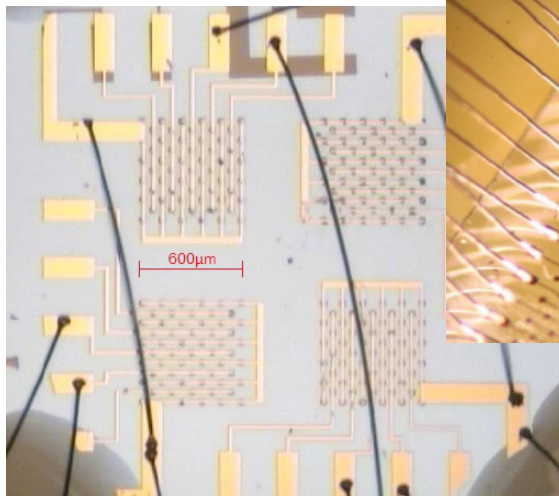
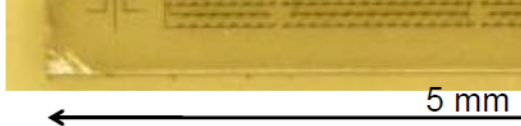
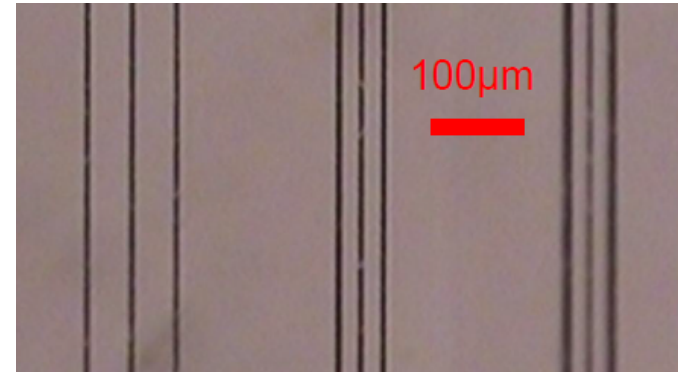
University of Manchester,
CEA Saclay,
CERN,
ETH Zurich,
Ohio State University

Several Prototypes tested at
Diamond Light Source
('09, '10, '11, '13)
CERN test beam ('12)
RBI proton beam ('13).



3DDD - Femtosecond laser processing examples

all-carbon detector, 3D printing of 3DDD(!), S. Lagomarsino, INFN

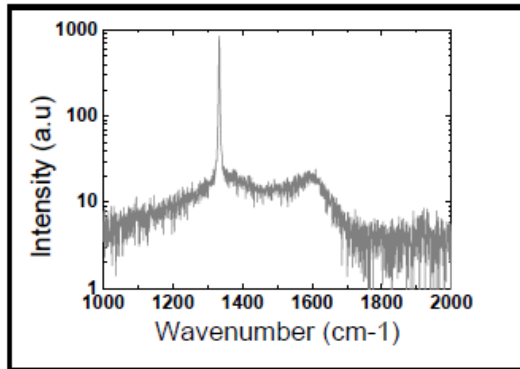


Appl. Phys. Lett. 105, 231105 (2014)

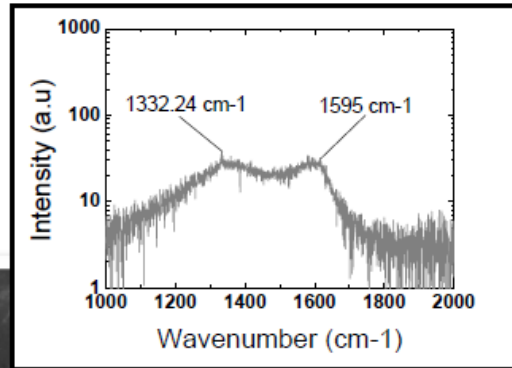
3DDD - Graphitic columns - Structure

Raman Analysis

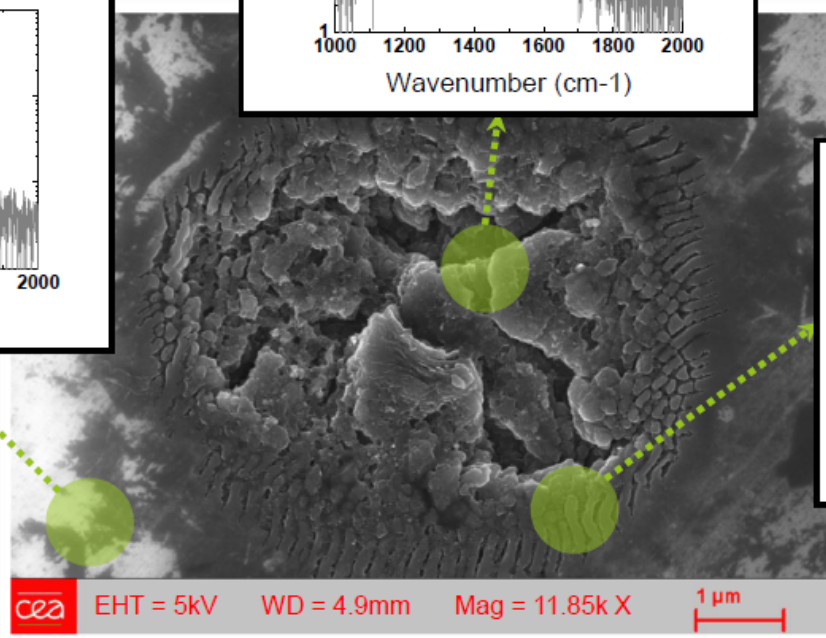
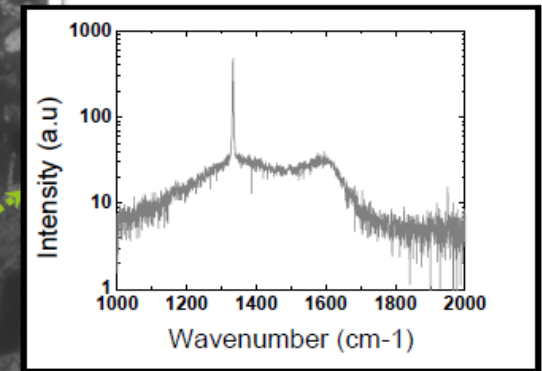
□ Diamond



□ Electrode



□ Border

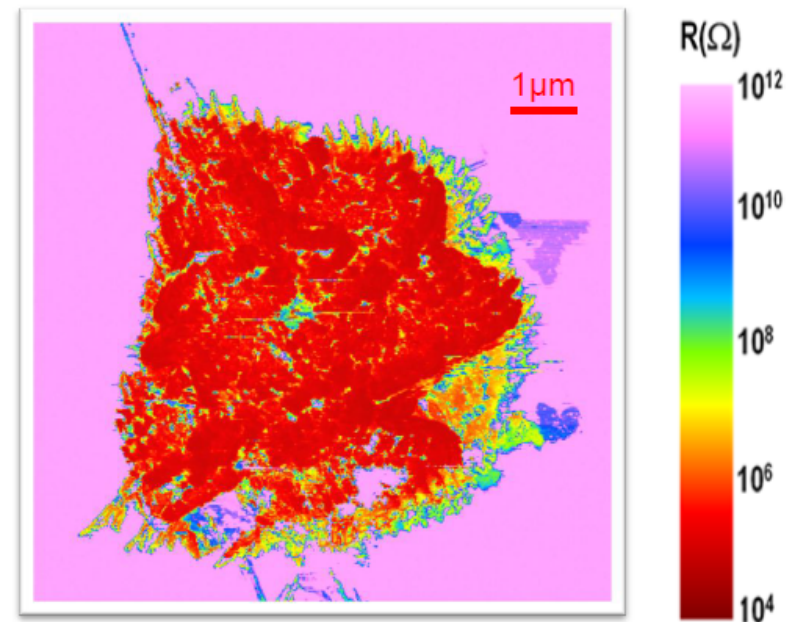
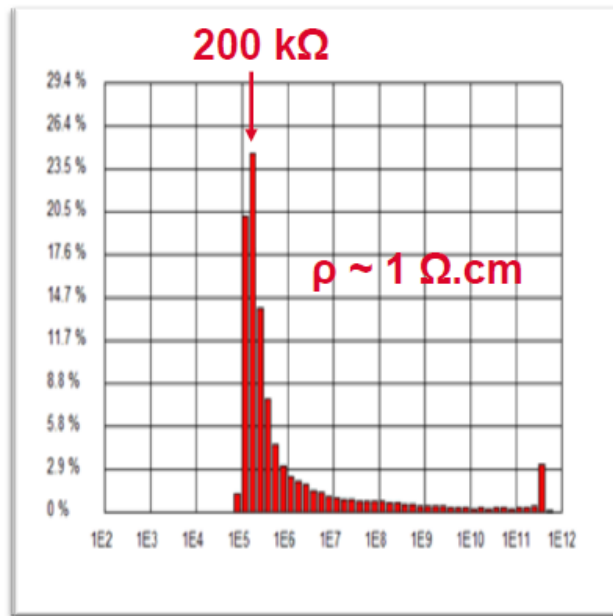
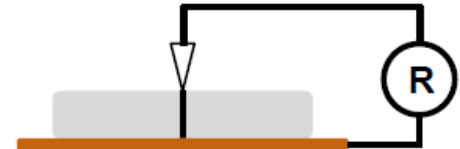


cea EHT = 5kV WD = 4.9mm Mag = 11.85k X 1 μm

3DDD - Graphitic columns - Resistivity

AFM measurements courtesy J. Alvarez (Laboratoire de Génie Electrique de Paris)

Electrode mapping using Conductive probe AFM



Resistance distribution in the mapping area

Resistance mapping

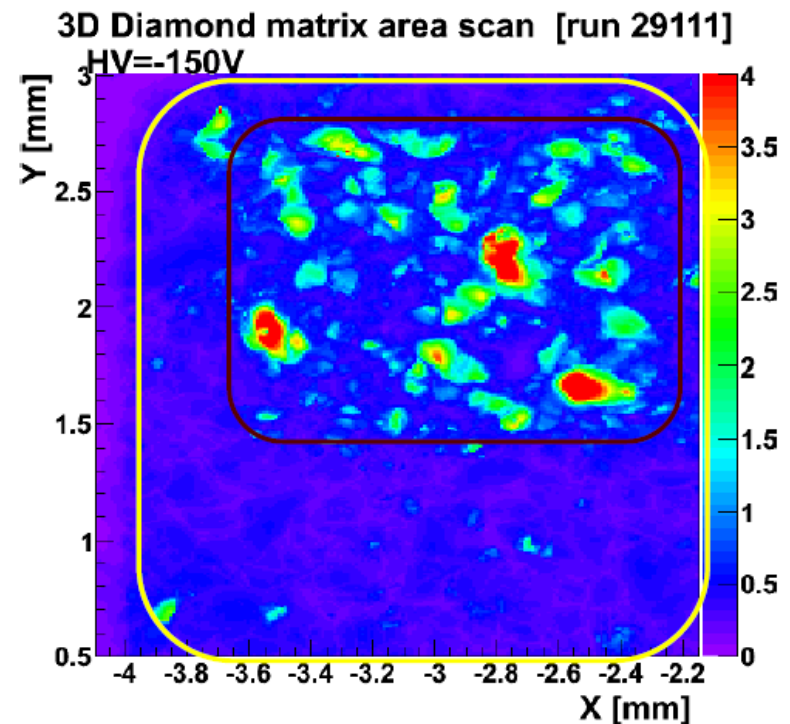
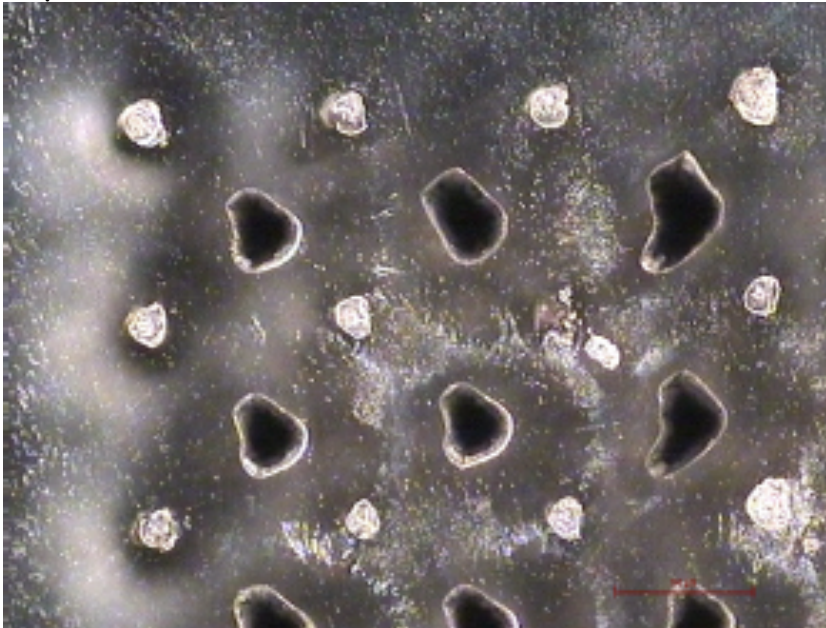
0.022 Ωcm reported in Appl. Phys. Lett. 105, 231105 (2014)

3DDD - Charge Collection Characteristics - pcCVD

First hint for higher CCE: 2011 beamtime @ Diamond Light Source, UK

Raster scan with X-ray microbeam 15 keV, 4 microns spot FWHM, 10^9 photons/s

'crude' 3D structure, matrix of cones, covered with planar metal electrodes [1064nm ns YAG laser]

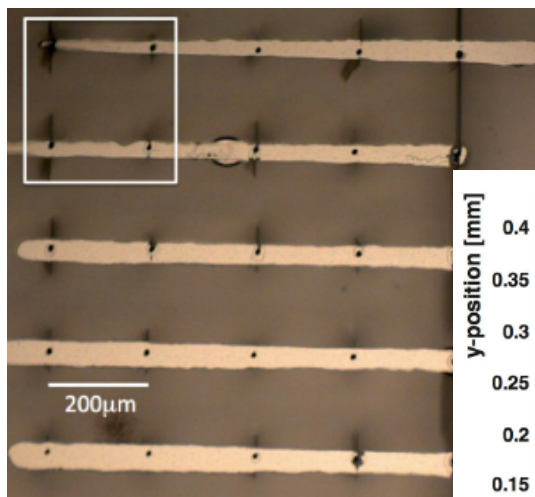


XBIC of the pcCVD sample

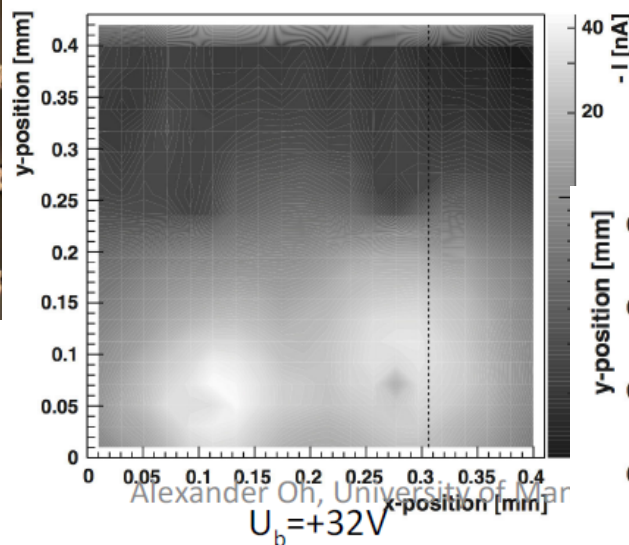
3DDD - Charge Collection Characteristics - scCVD

First scCVD [3ns 337nm N laser, ~3microJ]:

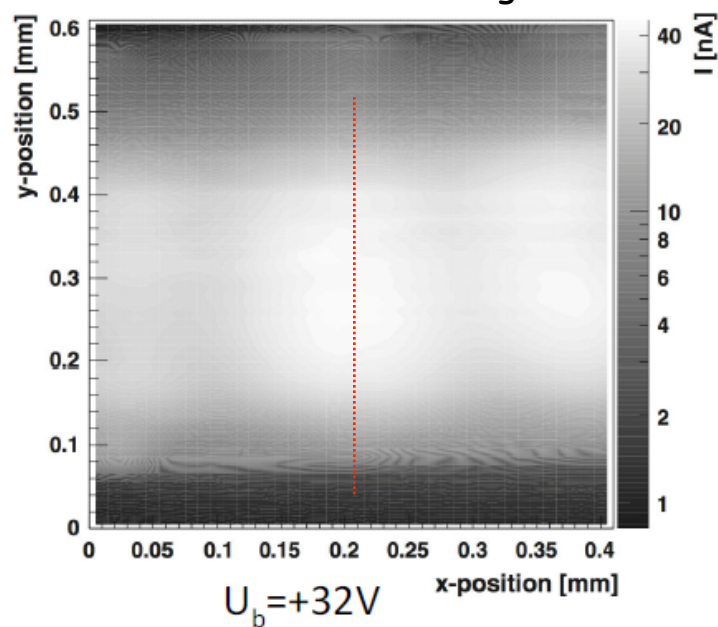
2012 beamtime @ Diamond Light Source, UK



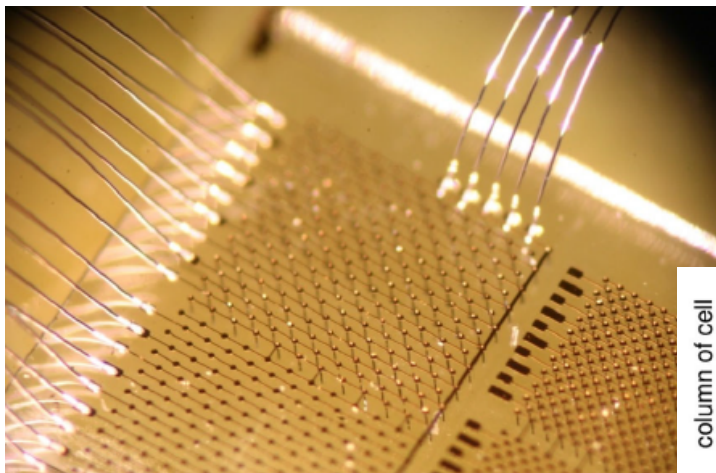
XBIC front shooting



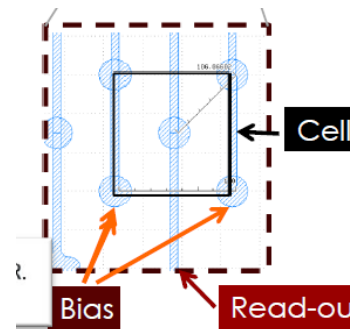
XBIC side shooting



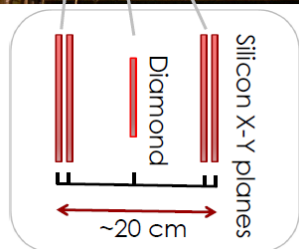
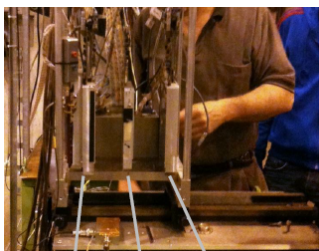
3DDD - Charge Collection Characteristics - scCVD



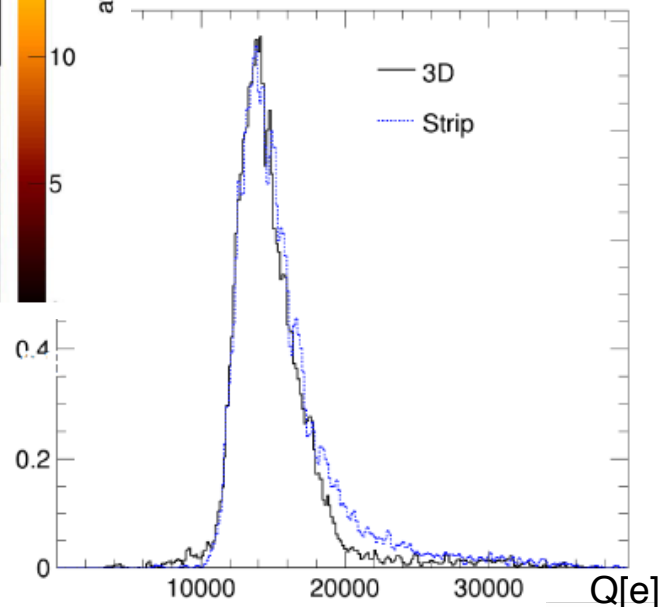
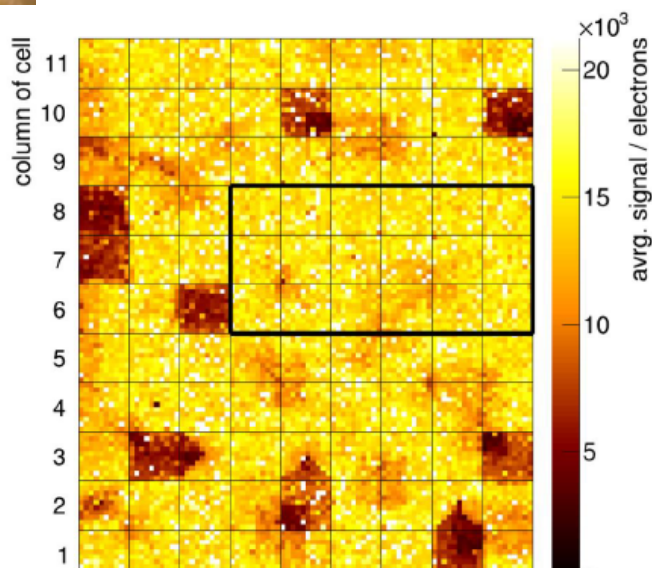
EG scCVD [100fs 800 nm laser, ~1microJ]
500 microns scCVD (3D structure+strips+3D only metal pattern)
cubic cell base size 150 microns (99 cells)



CERN Test-beam set-up 2013

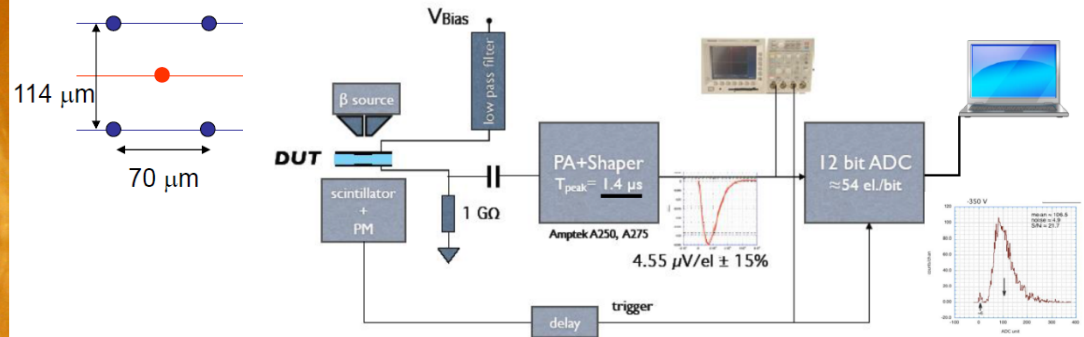
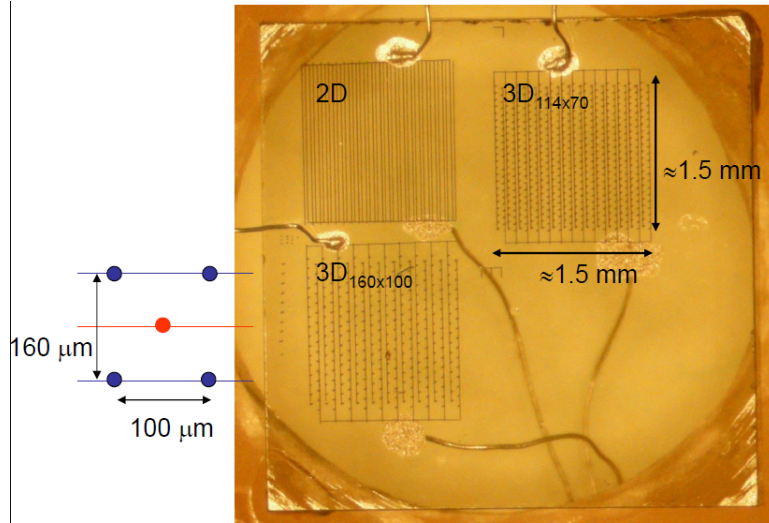


- protons with $p=120 \text{ GeV/c}$
- spill every 40 sec
- ~4k events / spill
- readout VA2 low-noise CMOS
- silicon telescope for track rec.



3DDD - Charge Collection Characteristics - pcCVD

all content here from: http://www-adamas.gsi.de/ADAMAS03/talks/Lagomarsino_INFN.pdf

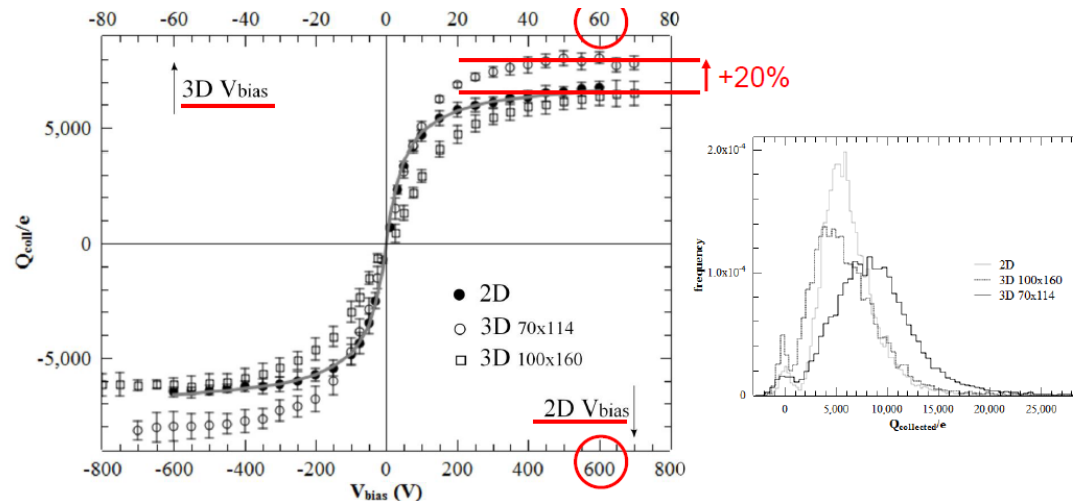


EG pcCVD [30fs, 800nm laser]

Saturation occurs at voltages ten times lower for the 3D compared with 2D sensors.

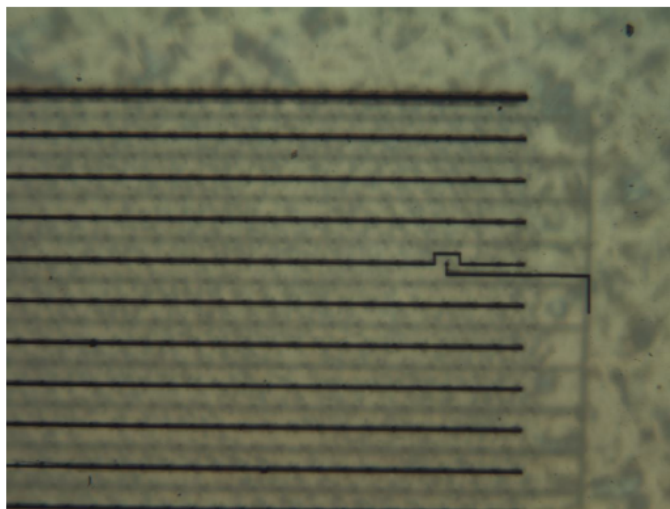
3D have a higher efficiency compared with 2D sensors ($\approx 20\%$), if the electrodes inter-distance is small enough ($< 100\mu\text{m}$).

The separations of the 10% percentile of the distribution from the pedestal are comparable for 2D and 3D detectors.

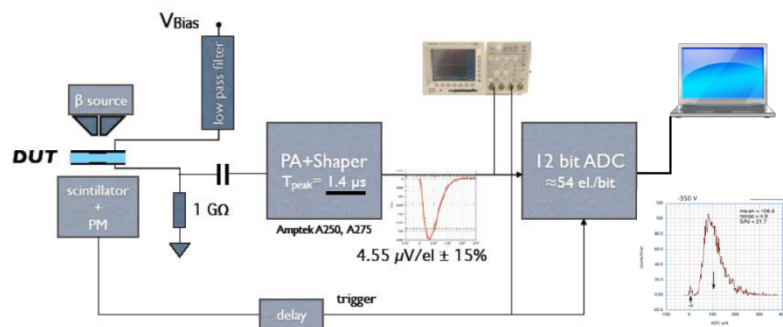


3DDD - Charge Collection Characteristics - DoI

all content here from: http://www-adamas.gsi.de/ADAMAS03/talks/Lagomarsino_INFN.pdf

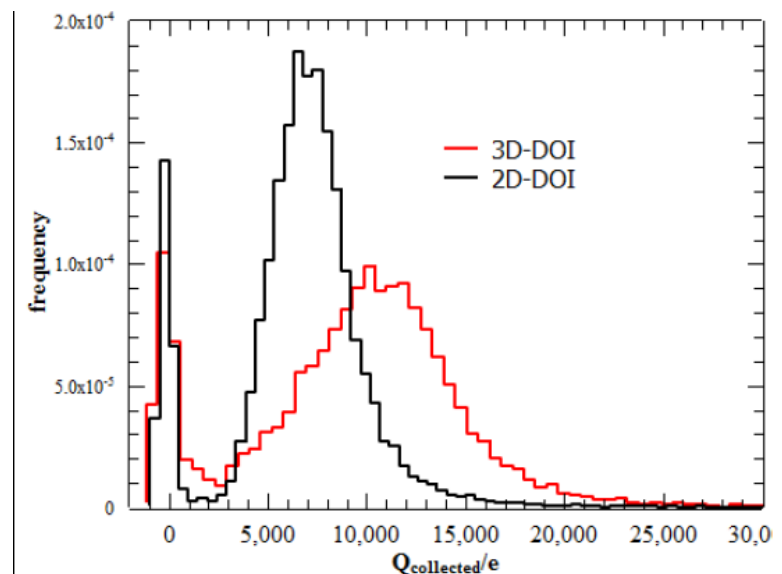


We fabricated a **3D**
70x114 sensor and a
planar sensor also in a
DOI sample grown at
Augsburg University



→ 2D (at 600 V) = 7600 e (39% CCE)

→ **3D** (at 140 V) = 11000 e (58% CCE), **relative gain +50%**



LA pcCVD: electronic grade pcCVD (e6) fulfil all requirements for hadrontherapy (C) diamond hodoscope (but need real LA)

3D Diamond Detectors: it works!

all-carbon detector with laser 3D printing of ready to use 3DDD
scCVD same CCE as planar at much lower bias
pcCVD + DoI increase in CCE for 3D geometry

to optimise:

production yield (~ 90% now) of the graphitic columns
lower resistivity of columns (few kOhms for 500 microns now)
higher radiation hardness of 3DDD to be confirmed

Thank you for your attention!